

STRUCTURE Silicon Monolithic Integrated Circuit

PRODUCT SERIES Single-Phase Full-Wave Motor Pre-Driver for Fan

TYPE BA6423AF

FEATURES Lock detection, Automatic restart circuit

# **OABSOLUTE MAXIMUM RATINGS**

Parameter	Symbol	Limit	Unit
Supply voltage	Vcc	30	V
Power dissipation	Pd	780 *	mW
Operating temperature	Topr	-40 <b>~</b> +100	ο̂
Storage temperature	Tstg	-55 <b>~</b> +150	°C
Output current	Iomax	1.0 * *	Α
Output voltage	VOUT	30	V
AL signal output voltage	VAL	30	V
Junction temperature	Tjmax	150	°C

<sup>\*</sup> Reduce by 6.24mW/°C over 25°C. (On 70.0mm × 70.0mm × 1.6mm glass epoxy board)

# **OOPERATING CONDITIONS**

Parameter	Symbol	Limit	Unit
Operating supply voltage range	Vcc	6.0~28.0	V
Hall input voltage range	VH	2.5~Vcc	V

<sup>\*</sup> This product is not designed for production against radioactive rays.

<sup>\* \*</sup> This value is not to exceed Pd.

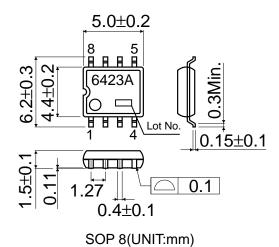
 $<sup>\</sup>ensuremath{\ast}$  This document may be strategic data subject to COCOM regulations.



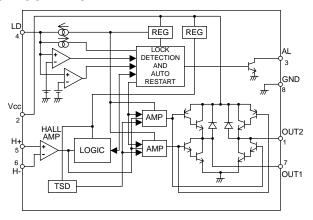
OELECTRICAL CHARACTERISTICS (Unless otherwise specified Ta=25°C,Vcc=12V)

$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$							,	
Circuit current  Charge current of capacitor for lock detection  Discharge current of capacitor for lock detection  Charge-discharge current ratio of capacitor for lock detection  Clamp voltage of capacitor for lock detection  Comparison voltage of capacitor for lock detection  Output voltage H  VALL  AL terminal voltage L  VALL  ICC  2.7  5.4  8.1  MAX.  M	Parameter	Symbol			<del></del>		Conditions	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$			Min.	Тур.	Max.	Oille	Conditions	
for lock detectionILDC1.553.104.65μ AVLD=1.8VDischarge current of capacitor for lock detectionILDD0.330.660.99μ AVLD=1.8VCharge-discharge current ratio of capacitor for lock detectionrCD3.04.76.4-rCD=ILDC/ILDDClamp voltage of capacitor for lock detectionVLDCL2.002.483.00VComparison voltage of capacitor for lock detectionVLDCP0.700.991.30VOutput voltage LVOL-0.81.2VIo=200mAOutput voltage HVOH-0.91.4VVoltage between output and VccAL terminal voltage LVALL-0.10.3VIAL=10mAAL terminal leak currentIALL-010μ AVAL=30V	Circuit current	Icc	2.7	5.4	8.1	mA	At output OFF	
for lock detectionILDD0.330.660.99μ AVLD=1.8VCharge-discharge current ratio of capacitor for lock detectionrCD3.04.76.4-rCD=ILDC/ILDDClamp voltage of capacitor for lock detectionVLDCL2.002.483.00VComparison voltage of capacitor for lock detectionVLDCP0.700.991.30VOutput voltage LVOL-0.81.2VIo=200mAOutput voltage HVOH-0.91.4VVoltage between output and VccAL terminal voltage LVALL-0.10.3VIAL=10mAAL terminal leak currentIALL-010μ AVAL=30V		ILDC	1.55	3.10	4.65	μΑ	VLD=1.8V	
of capacitor for lock detection Clamp voltage of capacitor for lock detection VLDCL 2.00 2.48 3.00 V Comparison voltage of capacitor for lock detection Cutput voltage L VOL - 0.8 1.2 V Io=200mA		ILDD	0.33	0.66	0.99	μΑ	VLD=1.8V	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		rCD	3.0	4.7	6.4	-	rCD=ILDC/ILDD	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		VLDCL	2.00	2.48	3.00	V		
Output voltage H VOH - 0.9 1.4 V Voltage between output and Vcc AL terminal voltage L VALL - 0.1 0.3 V IAL=10mA AL terminal leak current IALL - 0 10 $\mu$ A VAL=30V		VLDCP	0.70	0.99	1.30	V		
VOH         -         0.9         1.4         V         Voltage between output and Vcc           AL terminal voltage L         VALL         -         0.1         0.3         V         IAL=10mA           AL terminal leak current         IALL         -         0         10         μ A         VAL=30V	Output voltage L	VOL	-	0.8	1.2	V	Io=200mA	
AL terminal voltage L         VALL         -         0.1         0.3         V         IAL=10mA           AL terminal leak current         IALL         -         0         10         μ A         VAL=30V	Output voltage H						Io=-200mA	
AL terminal leak current IALL - 0 10 μA VAL=30V		VOH	-	0.9	1.4	V		
	AL terminal voltage L	VALL	-	0.1	0.3	V	IAL=10mA	
Hall input - output offset voltage VOFS -20 0 20 mV	AL terminal leak current	IALL	-	0	10	μΑ	VAL=30V	
	Hall input - output offset voltage	VOFS	-20	0	20	mV		

# **OPACKAGE OUTLINES**



# **OBLOCK DIAGRAM**



# OTerminal name

Pin No.	Terminal		
	name		
1	OUT2		
2	Vcc		
3	AL		
4	LD		
5	H+		
6	H-		
7	OUT1		
8	GND		



#### OCautions on use

#### 1) Absolute maximum ratings

An excess in the absolute maximum rations, such as supply voltage, temperature range of operating conditions, etc., can break down the devices, thus making impossible to identify breaking mode, such as a short circuit or an open circuit. If any over rated values will expect to exceed the absolute maximum ratings, consider adding circuit protection devices, such as fuses.

#### 2) Connecting the power supply connector backward

Connecting of the power supply in reverse polarity can damage IC. Take precautions when connecting the power supply lines. An external direction diode can be added.

## 3) Power supply line

Back electromotive force causes regenerated current to power supply line, therefore take a measure such as placing a capacitor between power supply and GND for routing regenerated current. And fully ensure that the capacitor characteristics have no problem before determine a capacitor value. (when applying electrolytic capacitors, capacitance characteristic values are reduced at low temperatures)

## 4) GND potential

The potential of GND pin must be minimum potential in all operating conditions. Also ensure that all terminals except GND terminal do not fall below GND voltage including transient characteristics. However, it is possible that the motor output terminal may deflect below GND because of influence by back electromotive force of motor. Malfunction may possibly occur depending on use condition, environment, and property of individual motor. Please make fully confirmation that no problem is found on operation of IC.

#### 5) Thermal design

Use a thermal design that allows for a sufficient margin in light of the power dissipation(Pd) in actual operating conditions.

#### 6) Inter-pin shorts and mounting errors

Use caution when positioning the IC for mounting on printed circuit boards. The IC may be damaged if there is any connection error or if pins are shorted together.

#### 7) Actions in strong electromagnetic field

Use caution when using the IC in the presence of a strong electromagnetic field as doing so may cause the IC to malfunction.

# 8) ASO

When using the IC, set the output transistor so that it does not exceed absolute maximum rations or ASO.

## 9) Thermal shut down circuit

The IC incorporates a built-in thermal shutdown circuit (TSD circuit). Operation temperature is 175°C(typ.) and has a hysteresis width of 25°C(typ.). When IC chip temperature rises and TSD circuit works, the output terminal becomes an open state. TSD circuit is designed only to shut the IC off to prevent thermal runaway. It is not designed to protect the IC or guarantee its operation. Do not continue to use the IC after operation this circuit or use the IC in an environment where the operation of this circuit is assumed.

# 10) Testing on application boards

When testing the IC on an application board, connecting a capacitor to a pin with low impedance subjects the IC to stress. Always discharge capacitors after each process or step. Always turn the IC's power supply off before connecting it to or removing it from a jig or fixture during the inspection process. Ground the IC during assembly steps as an antistatic measure. Use similar precaution when transporting or storing the IC.

## 11) GND wiring pattern

When using both small signal and large current GND patterns, it is recommended to isolate the two ground patterns, placing a single ground point at the ground potential of application so that the pattern wiring resistance and voltage variations caused by large currents do not cause variations in the small signal ground voltage. Be careful not to change the GND wiring pattern of any external components, either.

# 12) Capacitor between output and GND

When a large capacitor is connected between output and GND, if Vcc is shorted with 0V or GND for some cause, it is possible that the current charged in the capacitor may flow into the output resulting in destruction. Keep the capacitor between output and GND below 100uF.

# 13) IC terminal input

When Vcc voltage is not applied to IC, do not apply voltage to each input terminal. When voltage above Vcc or below GND is applied to the input terminal, parasitic element is actuated due to the structure of IC. Operation of parasitic element causes mutual interference between circuits, resulting in malfunction as well as destruction in the last. Do not use in a manner where parasitic element is actuated.

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